

| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|-------|------|--|---|------------------|---------|------------------|
| S1 | 0 | 10/655179 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 06:15 |
| S2 | 1345 | (257/640,649,760).CCLS. | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2005/01/18 06:15 |
| S3 | 3668 | (438/257,724,744,754,757,769, 791,954).CCLS. | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2005/01/18 06:44 |
| S4 | 171 | ((silicon near nitride) Si\$1N\$1) with reduc\$3 near3 hydrogen | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 15:00 |
| S5 | 25 | S4 and ONO | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 08:09 |
| S6 | 0 | S4 with ONO | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 08:10 |
| S7 | 0 | S4 same ONO | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 08:10 |
| S8 | 2673 | ((silicon near nitride) Si\$1N\$1) with ONO | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 08:11 |
| S9 | 1666 | ((silicon near nitride) Si\$1N\$1) near5 ONO | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 08:11 |

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| S10 | 1167 | S9 and memory near3 cell | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 08:13 |
| S11 | 0 | S10 and charge near3 storage with reduc\$3 near hydrogen near2 content | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 08:14 |
| S12 | 908 | reduc\$3 near hydrogen near2 content | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 08:14 |
| S13 | 0 | (reduc\$3 near hydrogen near2 content) with charge near stor\$3 near layer | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 08:17 |
| S14 | 15 | (reduc\$3 near hydrogen near2 content) with silicon near nitride | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 08:18 |
| S15 | 0 | (reduc\$3 near hydrogen near2 content) with silicon near nitride with ONO | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 08:18 |
| S16 | 0 | (reduc\$3 near hydrogen near2 content) with (silicon near nitride) with ONO | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 08:18 |
| S17 | 2673 | ((silicon near nitride) Si\$1N\$1) with ONO | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 08:19 |
| S18 | 1666 | ((silicon near nitride) Si\$1N\$1) near5 ONO | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 08:20 |
| S19 | 1250 | ((silicon near nitride) Si\$1N\$1) near3 ONO | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 08:20 |

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| S20 | 889 | ((silicon near nitride) Si\$1N\$1) near2 ONO | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 08:20 |
| S21 | 152 | ((silicon near nitride) Si\$1N\$1) near ONO | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 08:20 |
| S22 | 0 | S21 and chrg\$ near3 stor\$3 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 08:21 |
| S23 | 81 | S21 and charge near3 stor\$3 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 14:59 |
| S24 | 9772 | "Si3N4" | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 09:12 |
| S25 | 0 | "Si3N4" near5 charg\$3 near stor\$4 near layer | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 09:13 |
| S26 | 2 | "Si3N4" near5 charg\$3 near stor\$4 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 09:13 |
| S27 | 307 | (257/354).CCLS. | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2005/01/18 15:00 |
| S28 | 0 | S27 and ((silicon near nitride) Si\$1N\$1) with reduc\$3 near3 hydrogen | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 15:49 |
| S29 | 41 | S27 and (ONO (silicon near oxide near5 silicon near nitride near5 silicon near oxide)) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 15:15 |

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| S30 | 1 | S29 and reduc\$3 near3 hydrogen | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 15:03 |
| S31 | 1 | S29 and charg\$3 near storage | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 15:11 |
| S32 | 1 | S27 and ONO | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 15:13 |
| S33 | 40 | S29 and gate | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 15:44 |
| S34 | 20 | S33 and charge | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 15:17 |
| S35 | 2 | S33 and charge near3 storage | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 15:46 |
| S36 | 266 | S27 not S29 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 15:45 |
| S37 | 4 | S36 and charge near3 storage | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 15:46 |
| S38 | 91 | S36 and ((silicon near nitride) Si\$1N\$1) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 15:54 |
| S39 | 31 | S36 and ((silicon near nitride) Si\$1N\$1) and charge | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 16:18 |

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| S40 | 2 | S36 and ((silicon near nitride) Si\$1N\$1) and charge near storage | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 15:55 |
| S41 | 9934 | charge near3 (strap\$4 trap\$4 nitride) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 16:18 |
| S42 | 323586 | sonos monos mnos | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 16:19 |
| S43 | 1326 | S41 and S42 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 16:20 |
| S44 | 323586 | 15same S42 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 16:20 |
| S45 | 674 | S41 same S42 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 16:21 |
| S46 | 480 | S41 with S42 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 16:21 |
| S47 | 97389 | ono | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 16:21 |
| S48 | 285 | S46 and S47 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 16:21 |
| S49 | 856613 | hydrogen | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 16:22 |

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| S50 | 24 | S48 and S49 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 16:22 |
| S51 | 290 | S49 near5 atomic:adj:percent\$4 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 16:25 |
| S52 | 1 | S48 and S51 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 16:25 |
| S53 | 14781 | S49 near5 percent\$4 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 16:25 |
| S54 | 1 | S48 and S53 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/01/18 16:25 |